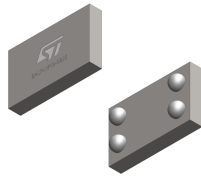
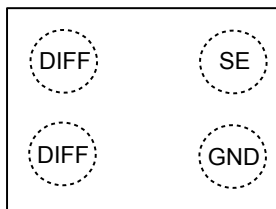


## 50 $\Omega$ ultra thin balun with integrated harmonic filter / conjugate match balun to ST BlueNRG-134 and BlueNRG-234



Flip-Chip (4 bumps) package



Top view

**Product status link**
[BALF-NRG-02J5](#)

### Features

- 50  $\Omega$  nominal input / conjugate match to STMicroelectronics chips BlueNRG-134 WLCSP and BlueNRG-234 WLCSP
- Low insertion loss
- Low amplitude imbalance
- Low phase imbalance
- Ultraminiature footprint: < 1.2 mm<sup>2</sup>
- Extra low profile < 350  $\mu$ m after reflow
- High RF performance
- RF BOM and area reduction

### Applications

- 2.45 GHz impedance matched balun filter
- Optimized for STMicroelectronics chip set BlueNRG-134 and BlueNRG-234 WLCSP
- Wearable applications

### Description

This device is an ultraminiature extra thin balun that integrates matching network and harmonics filter.

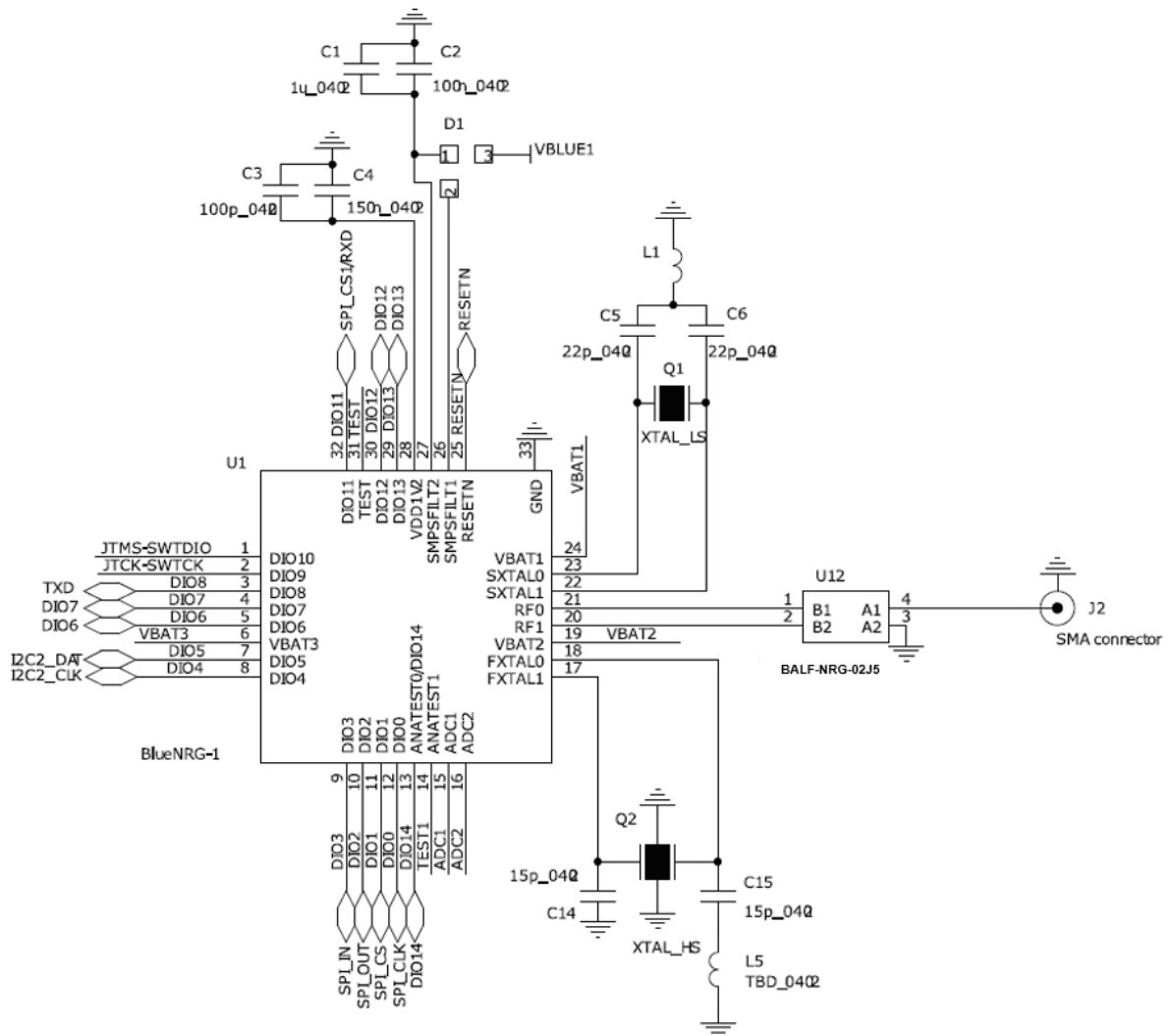
Matching impedance has been customized for the BLUENRG-134 and BlueNRG-234 WLCSP from STMicroelectronics.

Based on IPD technology on high resistivity silicium it optimizes the RF performance.

STMicroelectronics qualified this product intended to be used in system in package module based on standard reliability procedure. For more details, please contact ST representatives.

It is the responsibility of the customer to perform qualification reliability verifications as it is related to customer specific application, mission profile and module design, process.

# 1 Characteristics

**Figure 1. Application schematic**

**Table 1. Absolute ratings (limiting values)**

| Symbol    | Parameter   | Value |      |      | Unit |
|-----------|---|-------|------|------|------|
|           |   | Min.  | Typ. | Max. |      |
| $P_{IN}$  | Input power $RF_{IN}$   |       | -    | 10   | dBm  |
| $V_{ESD}$ | ESD ratings human body model (JESD22-A114-C), all I/O one at a time while others connected to GND | 2000  | -    |      | V    |
|           | ESD ratings charge device model (JESD22-C101-C)   | 500   | -    |      |      |
|           | ESD ratings machine model, all I/O  | 200   | -    |      |      |
| $T_{OP}$  | Operating temperature   | -40   | -    | +105 | °C   |

**Table 2. Impedances ( $T_{amb} = 25\text{ °C}$ )**

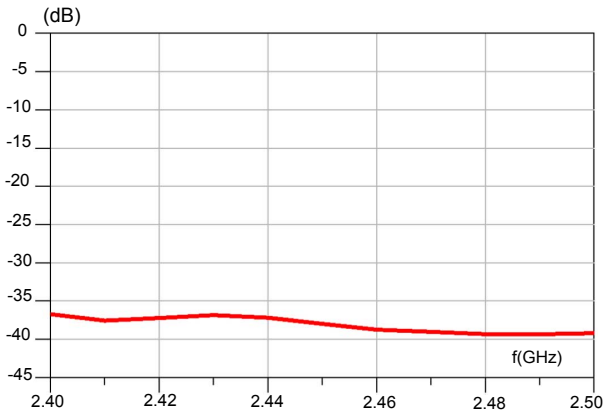
| Symbol     | Parameter                      | Value |         |      | Unit     |
|------------|--------------------------------|-------|---------|------|----------|
|            |                                | Min.  | Typ.    | Max. |          |
| $Z_{DIFF}$ | Nominal differential impedance | -     | matched | -    | $\Omega$ |
| $Z_{SE}$   | Nominal single ended impedance | -     | 50      | -    | $\Omega$ |

**Table 3. RF performance ( $T_{amb} = 25\text{ °C}$ )**

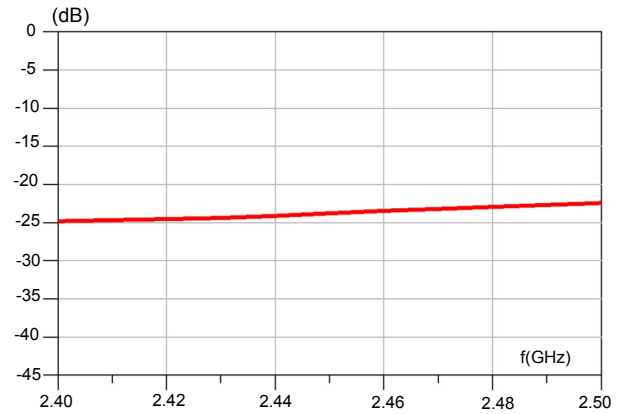
| Symbol       | Parameter   | Value |      |      | Unit       |
|--------------|---|-------|------|------|------------|
|              |   | Min.  | Typ. | Max. |            |
| f            | Frequency range (bandwidth)                               | 2400  |      | 2500 | MHz        |
| $I_L$        | Insertion loss in bandwidth (differential mode)           |       | 1.35 | 1.65 | dB         |
| $RL_{SE}$    | Single ended return loss in bandwidth (differential mode) | 26    | 34   |      | dB         |
| $RL_{DIFF}$  | Differential return loss in bandwidth                     | 18    | 24   |      | dB         |
| H2           | Second harmonic attenuation (differential mode)           | 37    | 47   |      | dB         |
| H3           | Third harmonic attenuation (differential mode)            | 50    | 56   |      | dB         |
| H4           | Fourth harmonic attenuation (differential mode)           | 45    | 50   |      | dB         |
| H5           | Fifth harmonic attenuation (differential mode)            | 39    | 60   |      | dB         |
| H6           | Sixth harmonic attenuation (differential mode)            | 37    | 46   |      | dB         |
| H7           | Seventh harmonic attenuation (differential mode)          | 38    | 58   |      | dB         |
| $\Phi_{imb}$ | Phase imbalance   | -4.5  |      | 4.5  | $^{\circ}$ |
| $A_{imb}$    | Amplitude imbalance                                       | -1.1  |      | +1.1 | dB         |

## 1.1 On-board measurements

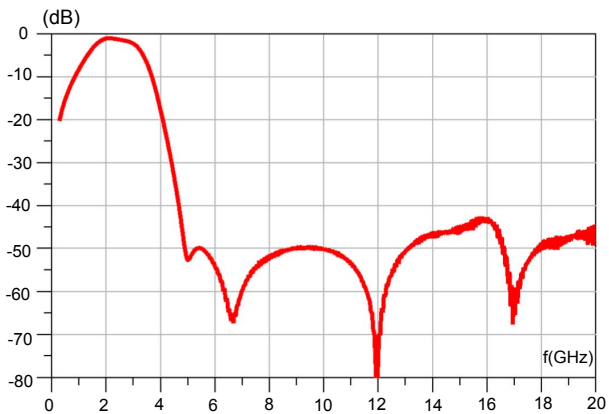
**Figure 2. Return loss on SE port ( $T_{amb} = 25\text{ °C}$ )**



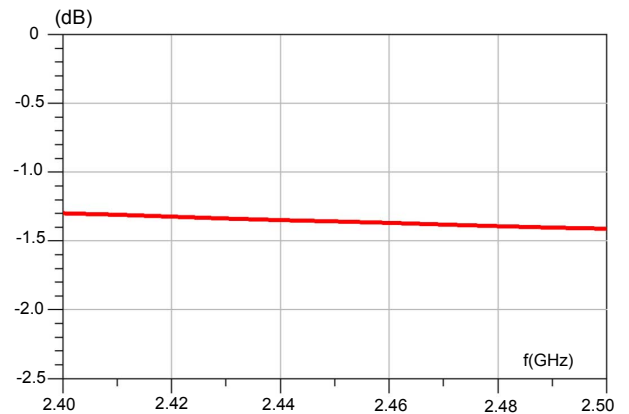
**Figure 3. Return loss on DIFF port ( $T_{amb} = 25\text{ °C}$ )**

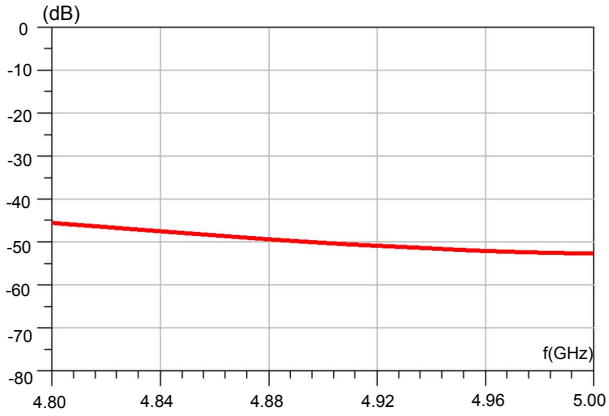
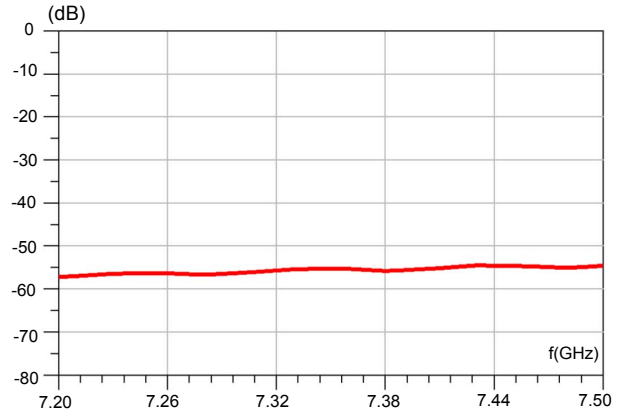
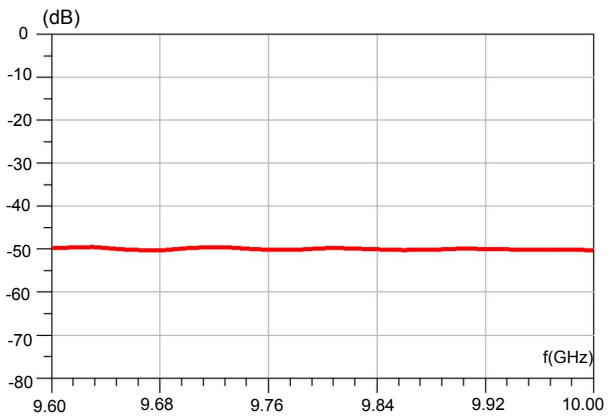
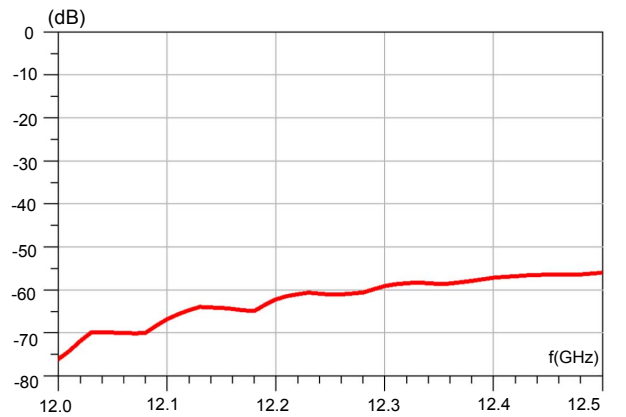
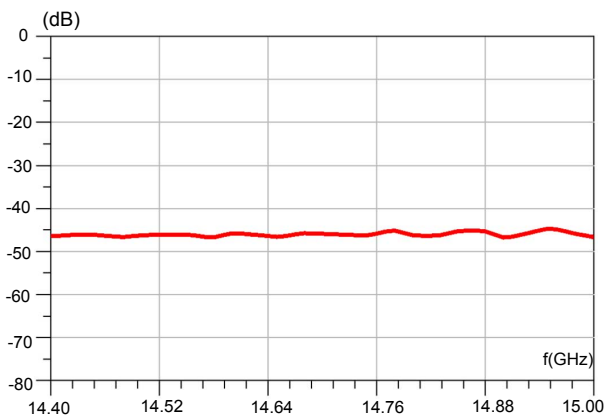
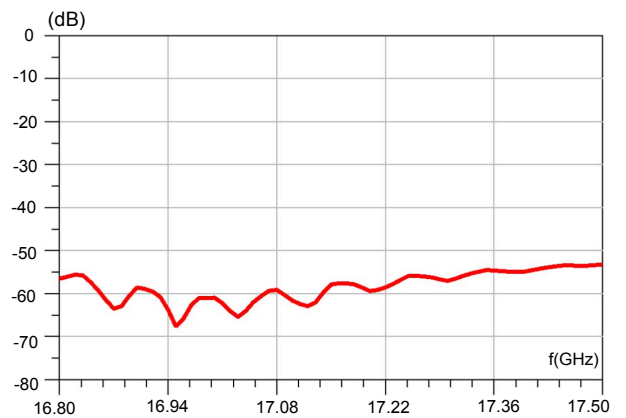


**Figure 4. Transmission ( $T_{amb} = 25\text{ °C}$ )**

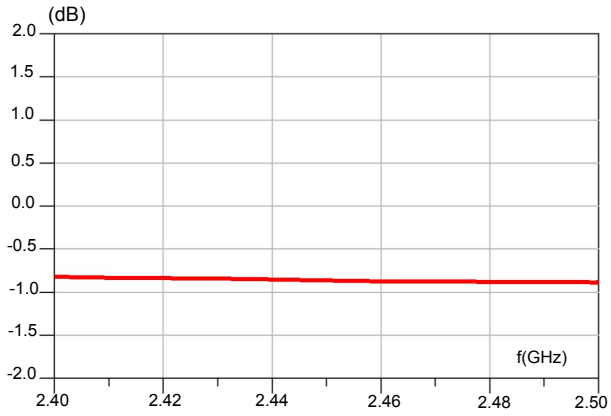


**Figure 5. Insertion loss ( $T_{amb} = 25\text{ °C}$ )**

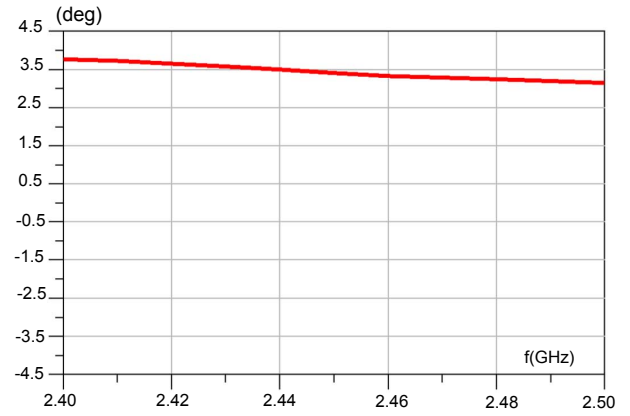


**Figure 6. H2 attenuation ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ )**

**Figure 7. H3 attenuation ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ )**

**Figure 8. H4 attenuation ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ )**

**Figure 9. H5 attenuation ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ )**

**Figure 10. H6 attenuation ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ )**

**Figure 11. H7 attenuation ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ )**


**Figure 12. Amplitude imbalance ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ )**



**Figure 13. Phase imbalance ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ )**



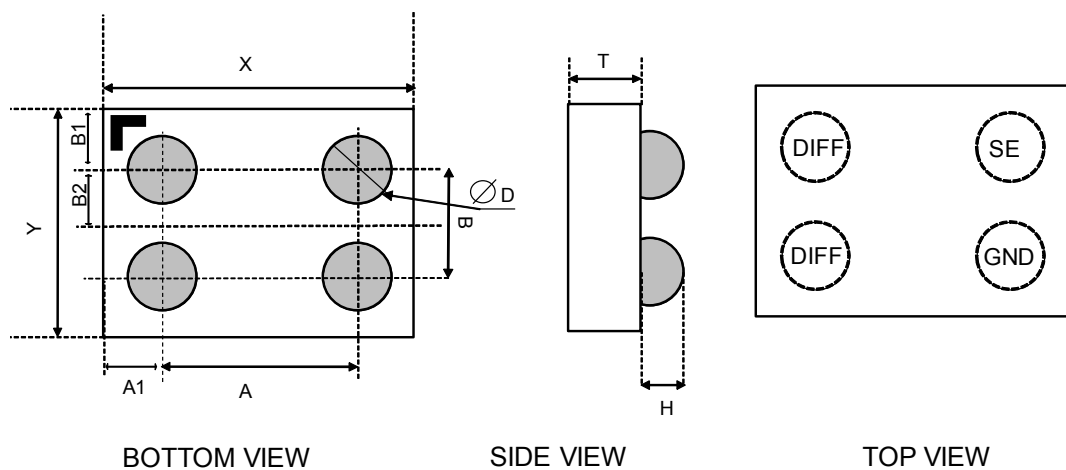
## 2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK® is an ST trademark.

### 2.1 Ultra thin Flip-Chip 4 bumps package information

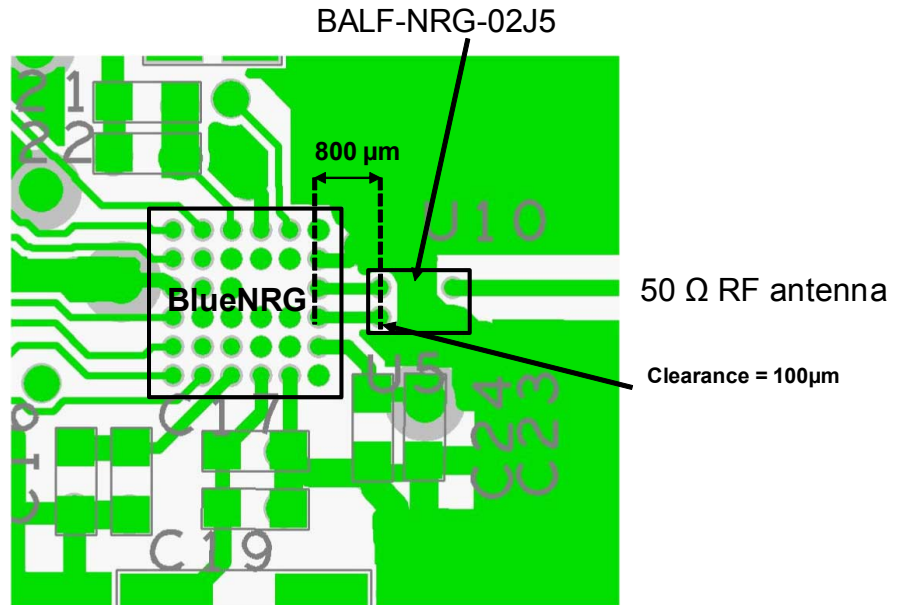
- Epoxy meets UL94, V0
- Lead-free package

**Figure 14. Ultra thin Flip-Chip 4 bumps package outline**



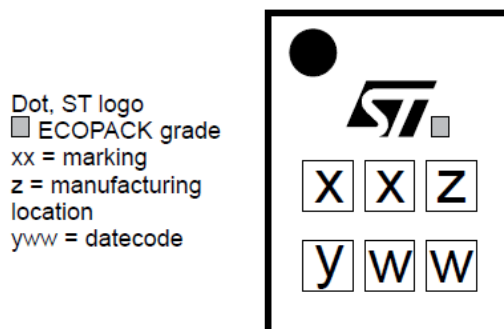
**Table 4. Ultra thin Flip-Chip 4 bumps package mechanical data**

| Parameter | Description                                   | Min. | Typ.  | Max. | Unit |
|-----------|---|------|-------|------|------|
| X         | X dimension of the die                        | 1355 | 1385  | 1415 | μm   |
| Y         | Y dimension of the die                        | 825  | 855   | 885  |      |
| A         | X pitch                                       |      | 1000  |      |      |
| B         | Y pitch                                       |      | 400   |      |      |
| A1        | Distance from bump to edge of die on X axis   |      | 192.5 |      |      |
| B1        | Distance from bump to edge of die on Y axis   |      | 227.5 |      |      |
| B2        | Distance from bump to center of die on Y axis |      | 200   |      |      |
| D         | Bump diameter                                 | 202  | 227   | 252  |      |
| T         | Substrate thickness                           | 190  | 200   | 210  |      |
| H         | Bump height                                   | 117  | 142   | 167  |      |

**Figure 15. Recommended land pattern**

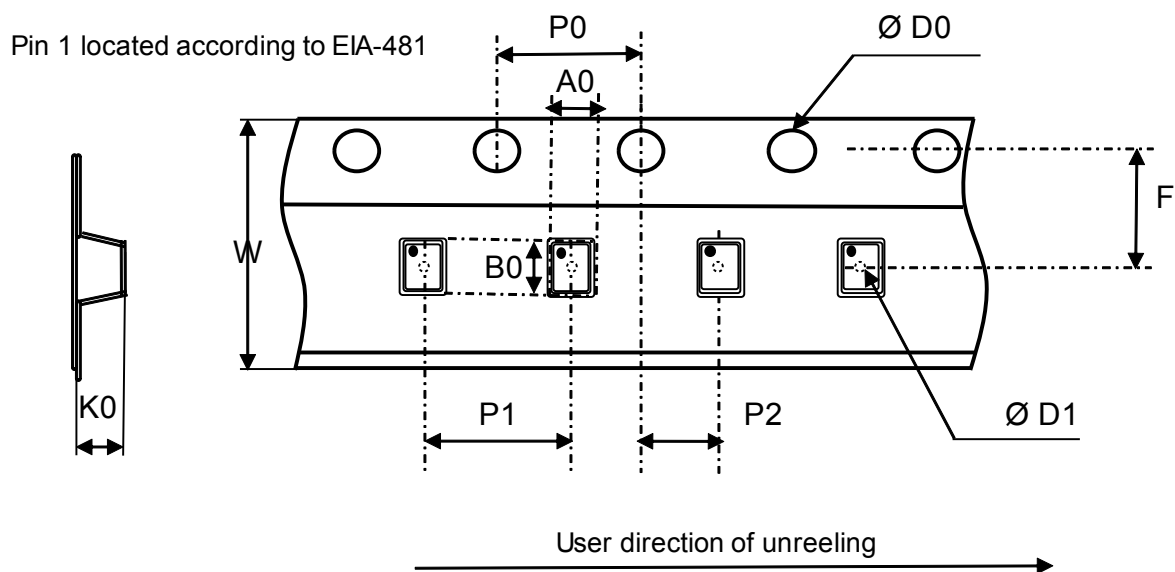


## 2.2 Ultra thin Flip-chip 4 bumps packing information

**Figure 16. Marking**


Note: More packing information is available in the application note:

- AN2348 Flip-Chip: "Package description and recommendations for use"

**Figure 17. Flip Chip tape and reel specification**


Note: Pocket dimensions are not on scale  
Pocket shape may vary depending on package

**Table 5. Ultra thin Flip-Chip 4 bumps package mechanical data**

| Ref. | Dimensions  |      |      |
|------|-------------|------|------|
|      | Millimeters |      |      |
|      | Min.        | Typ. | Max. |
| A0   | 0.91        | 0.96 | 1.01 |
| B0   | 1.44        | 1.49 | 1.54 |

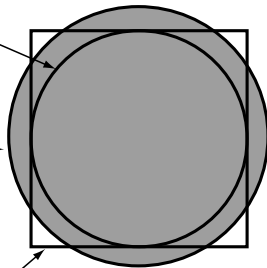
| Ref. | Dimensions  |      |      |
|------|-------------|------|------|
|      | Millimeters |      |      |
|      | Min.        | Typ. | Max. |
| P1   | 3.90        | 4.00 | 4.10 |
| P0   | 3.90        | 4.00 | 4.10 |
| Ø D0 | 1.40        | 1.50 | 1.60 |
| Ø D1 | 0.15        | 0.20 | 0.25 |
| F    | 3.45        | 3.50 | 3.55 |
| K0   | 0.38        | 0.43 | 0.48 |
| P2   | 1.95        | 2.00 | 2.05 |
| W    | 7.90        | 8.00 | 8.30 |

**Figure 18. Footprint - non solder mask defined**

Copper pad diameter:  
 220 µm recommended  
 180 µm minimum  
 260 µm maximum

Solder mask opening:  
 320 µm recommended  
 300 µm minimum  
 340 µm maximum

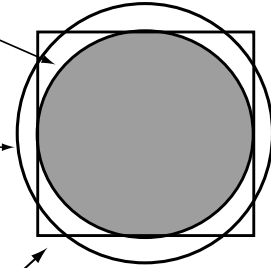
Solder stencil opening:  
 220 µm recommended


**Figure 19. Footprint - solder mask defined**

Solder mask opening:  
 220 µm recommended  
 180 µm minimum  
 260 µm maximum

Copper pad diameter:  
 320 µm recommended  
 300 µm minimum

Solder stencil opening:  
 220 µm recommended



### 3 Ordering information

Figure 20. Ordering information scheme

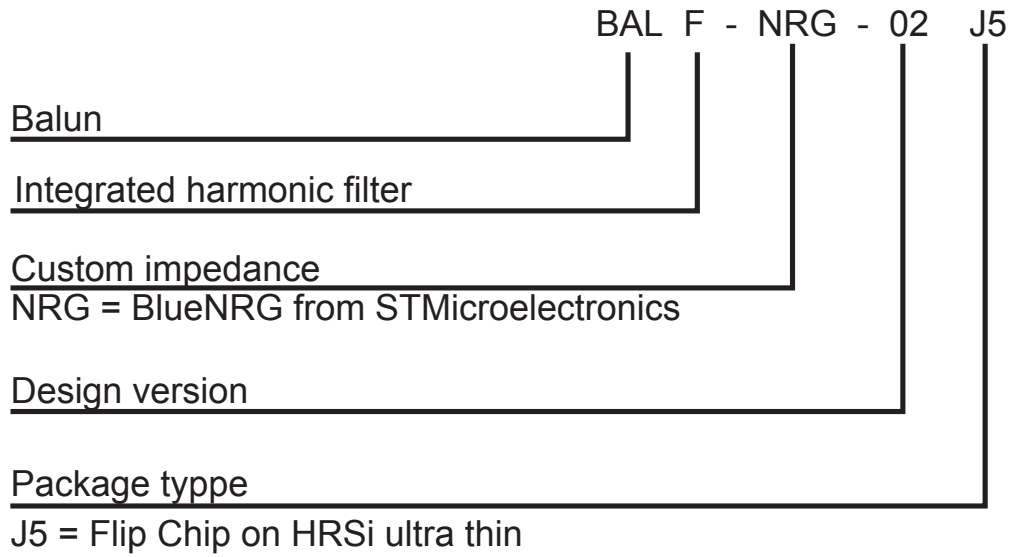


Table 6. Ordering information

| Order code    | Marking | Package           | Weight   | Base qty. | Delivery mode |
|---------------|---------|-------------------|----------|-----------|---------------|
| BALF-NRG-02J5 | TP      | Flip-Chip 4 bumps | 0.645 mg | 5000      | Tape and reel |

## Revision history

**Table 7. Document revision history**

| Date        | Revision | Changes          |
|-------------|----------|------------------|
| 12-Jul-2018 | 1        | Initial release. |

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